

# EE 332: Devices and Circuits II

## Course Review & Examples for the Final Exam

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# *What did we learn?*

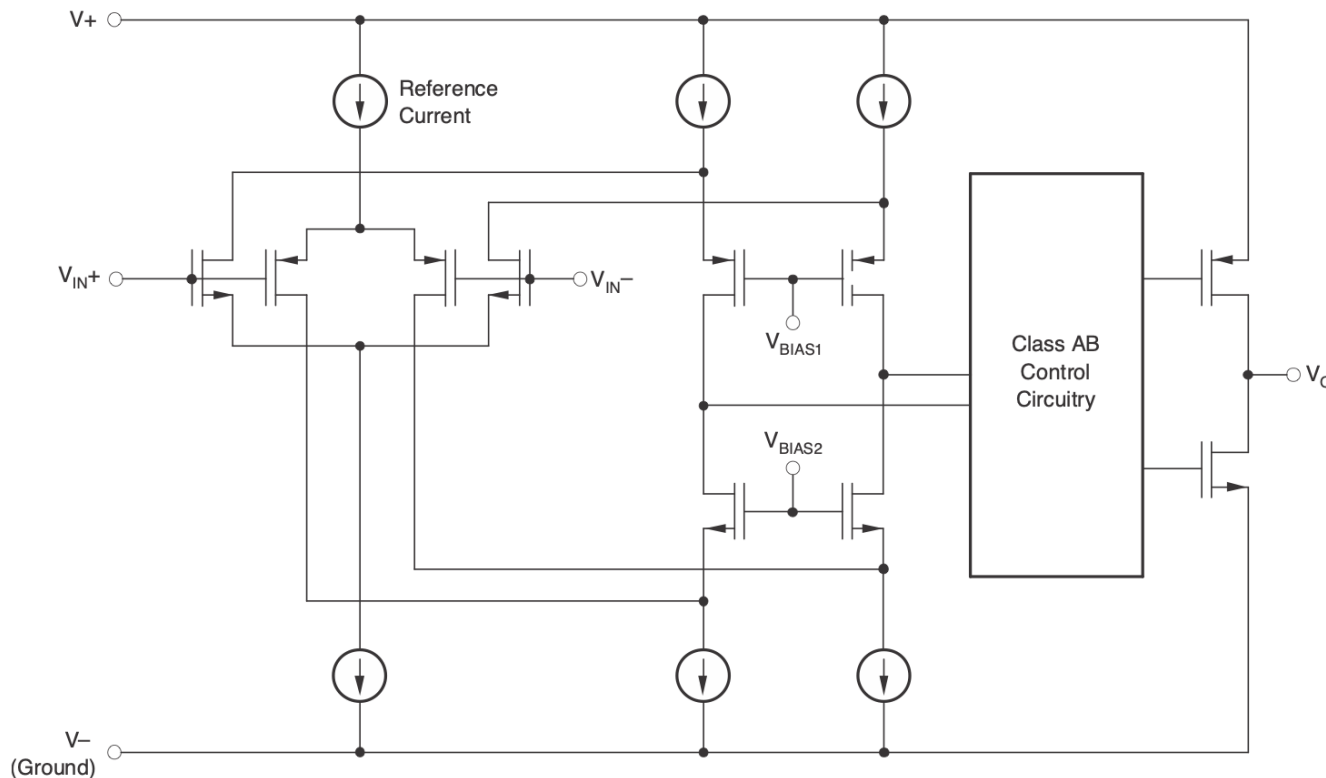
- MOS basics and modeling
  - I/V char, parasitics, small-signal, body-effect, channel length mod, ...
- Single-stage Amp (CS, CG, SF + Cascode)
- Differential Pair (DM vs. CM, single-ended vs. diff, ...)
- Frequency response (Poles/zeros, Bode Plot, Miller approx., GBW)
- Current Mirrors & Biasing
- Feedback (loop-gain, voltage-voltage fb, ...) & OpAmps
- Noise (Definition & Characterization, Thermal Noise, etc.)

# *Why did we learn?*

- Analog circuit is an inevitable part of any electrical system!
  - Remember the world is analog!
- Now you can clearly appreciate the benefit of digital processors
  - You know where the noise is coming from!
- All the metrics you learned are fundamentals that any IC and embedded system designer should know ...
  - Gain, Noise, Speed, ...
- Techniques and circuit analysis are also essential for any IC designer
- Topics like feedback, noise, ... are useful in Control, Signal processing, communications, etc.

# COT Example (CMOS): TI OPAx355

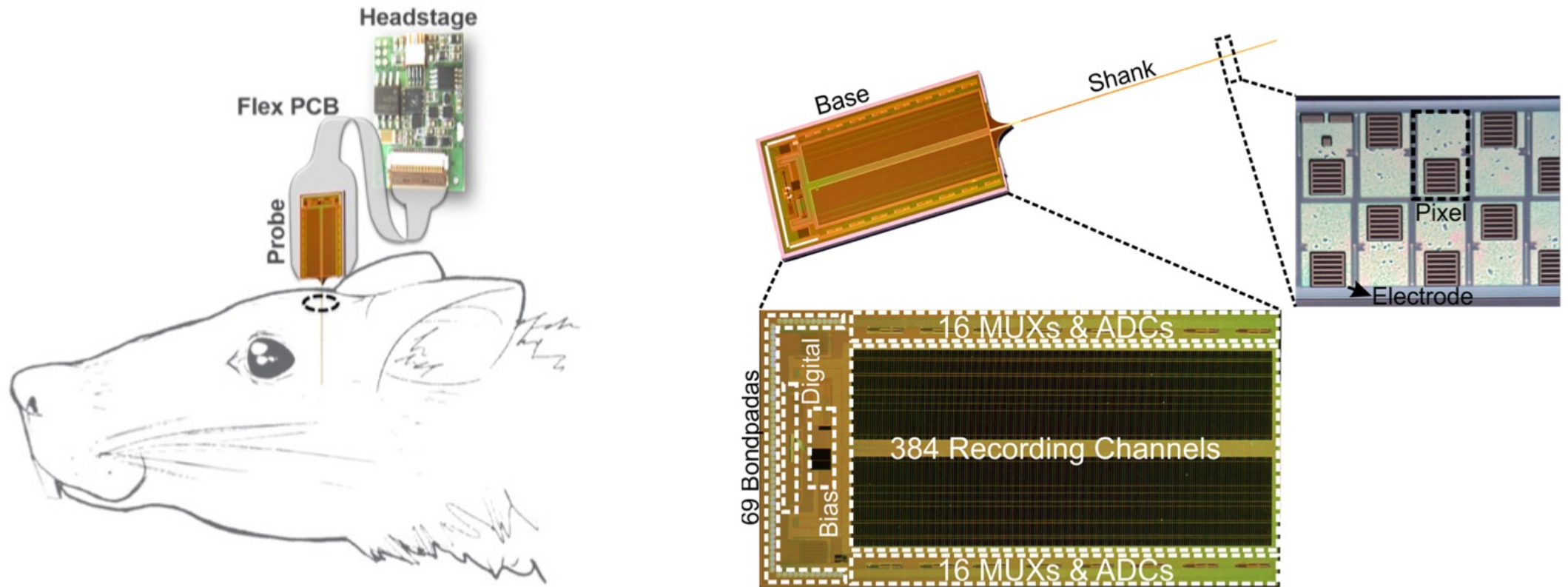
## 8.2 Functional Block Diagram



## 1 Features

- Unity-Gain Bandwidth: 450 MHz
- Wide Bandwidth: 200 MHz GBW
- Low Noise: 5.8 nV/ $\sqrt{\text{Hz}}$
- Excellent Video Performance
  - Differential Gain: 0.02%
  - Differential Phase: 0.05°
  - 0.1-dB Gain Flatness: 75 MHz
- Input Range Includes Ground
- Rail-to-Rail Output (within 100 mV)
- Low Input Bias Current: 3 pA
- Low Shutdown Current: 3.4  $\mu\text{A}$
- Enable and Disable Time: 100 ns and 30 ns
- Thermal Shutdown
- Single-Supply Operating Range: 2.5 V to 5.5 V
- *MicroSIZE* Packages

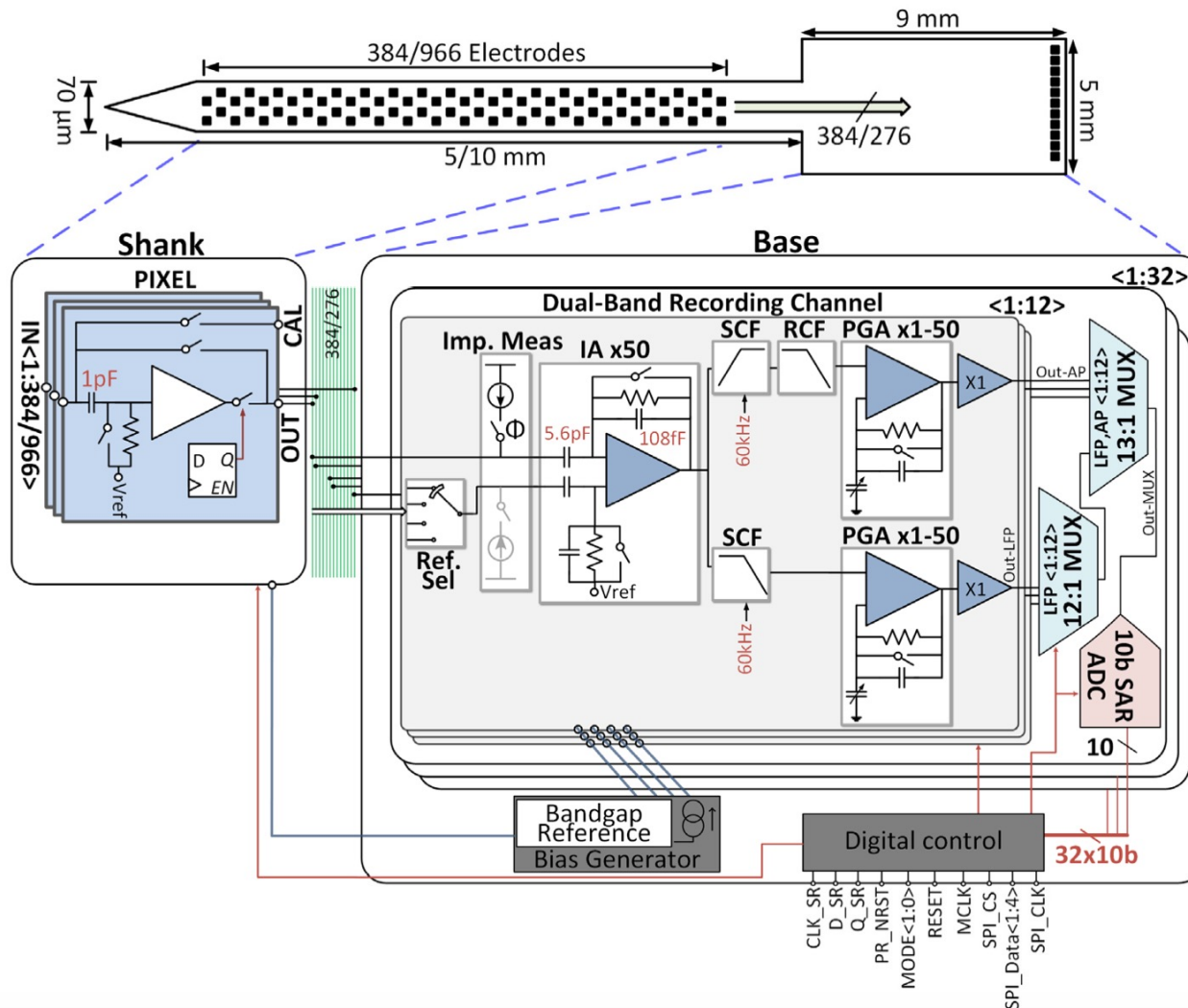
# Modern Examples: Neuropixel



Fully integrated silicon probes for high-density recording of neural activity [Nature 2017]

A Neural Probe with up to 966 Electrodes and up to 384 Configurable Channels in  $0.13\mu\text{m}$  SOI CMOS [TBioCAS 2017]

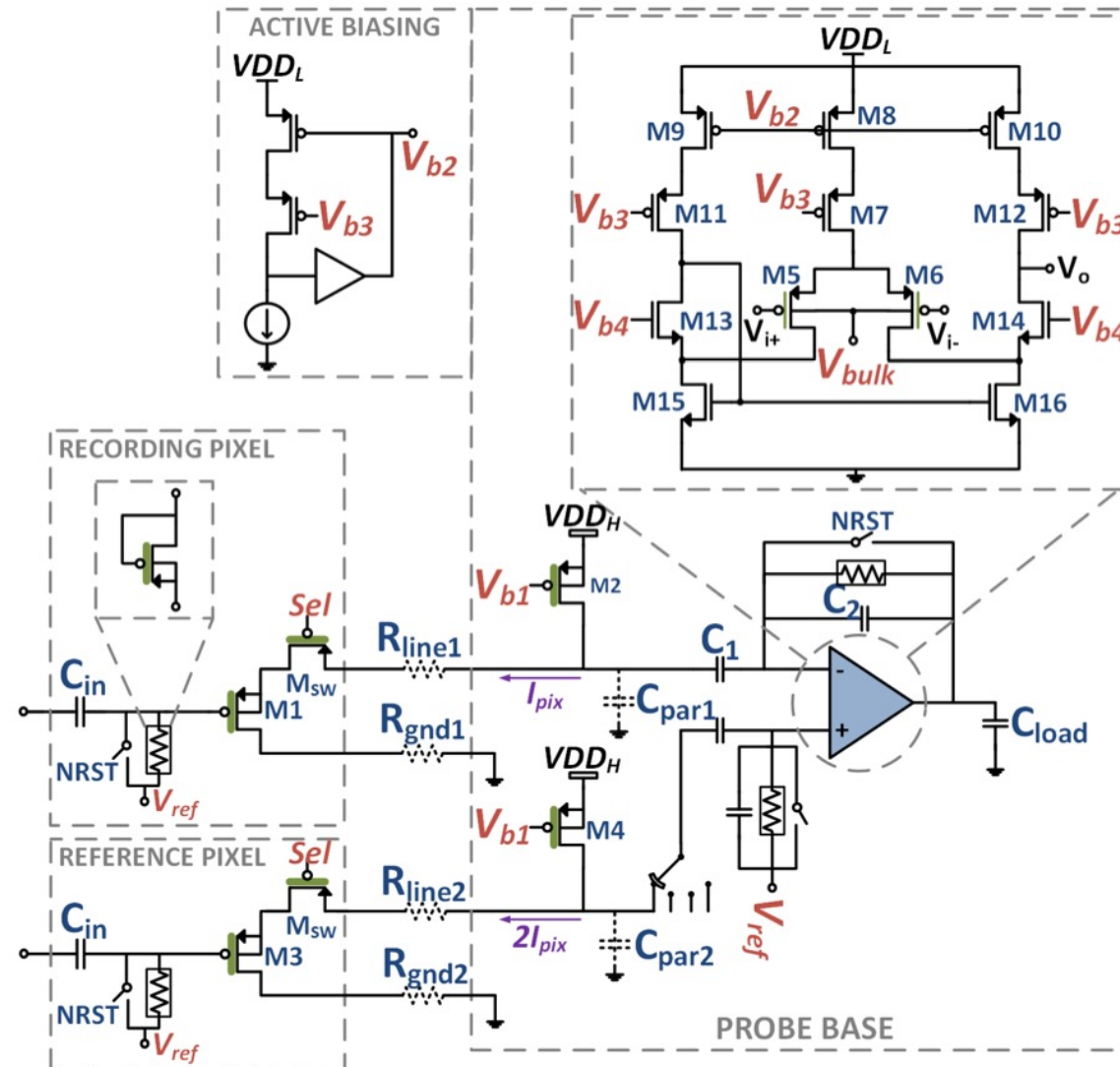
# Modern Examples: Neuropixel



**Extended Data Table 1 | Measured operating parameters of the 4 probe types reported (phase 3)**

	Option 1	Option 2	Option 3	Option 4
Site Count	384	384	960	966
Channel count	384	384	384	276
Electrode type	Passive	Active	Passive	Active
Shank power (mW)	0	1.31	0	1.31
Base power (mW)		17.5		
Electrode area ( $\mu\text{m}^2$ )		144		
Crosstalk (at 1kHz)		< 5%		
Gain		selectable from 50 - 2500		
AP band high-pass corner (kHz)		selectable from 0.3 - 1.0		
AP band low-pass corner (kHz)		10		
LFP band high-pass corner (Hz)		0.5		
LFP band low-pass corner (Hz)		1000		
AP band sampling rate (kHz)		30		
LFP band sampling rate (kHz)		2.5		
AP band noise ( $\mu\text{V}$ r.m.s.)	$5.7 \pm 0.8$	$6.6 \pm 0.8$	$5.5 \pm 0.7$	$6.6 \pm 2.5$
LFP band noise ( $\mu\text{V}$ r.m.s.)	$9.6 \pm 5.8$	$13.0 \pm 2.8$	$8.0 \pm 2.5$	$10.2 \pm 1.9$

# Modern Examples: Neuropixel

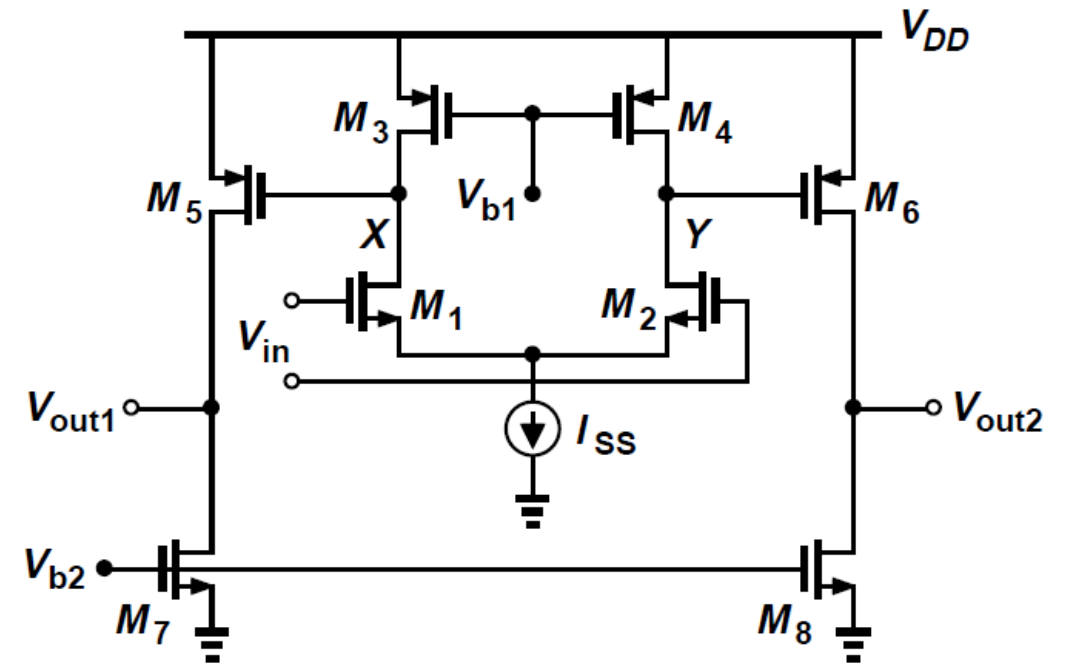


# Examples for the Final Exam



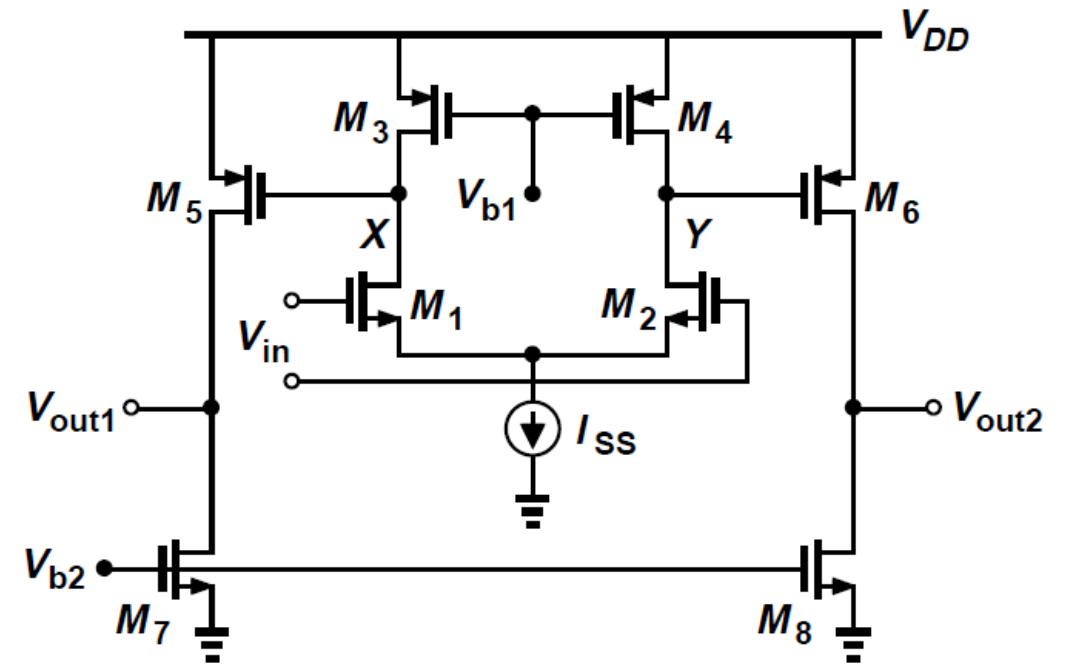
## Example 1

- Find/Draw: DM & CM half-circuit & gain, Swing



## Example 2

- Find: Poles & Bode plots ( $C_L=1\text{pF}$ ,  $C_{gs}=C_{gd}=1\text{fF}/\mu\text{m}$ ), 3db-bw, unity-gain bw



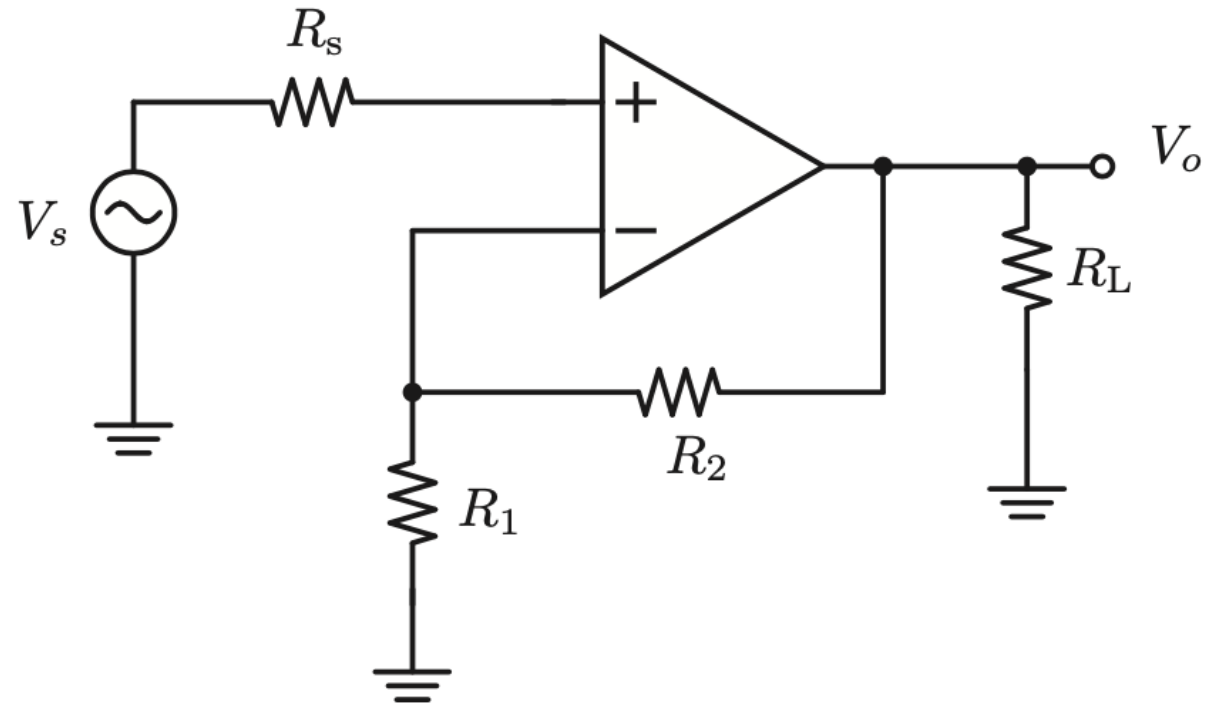
## Example 3

An op-amp is configured to provide gain ( $V_O/V_S$ ) of 5V/V a  $R_L = 1k\Omega$  load. Model the op-amp with the following parameters:

- $R_{in} = \infty$  (ideal)
- $R_{out} = 0$  (ideal)
- $A_0 = 100$  (not infinite)
- $f_0 = 10MHz$  (not ideal: finite 3dB-bandwidth frequency)

### Find:

- $R_2/R_1$  ?
- Gain error
- Bandwidth & Unity frequency
- If OpAmp's  $R_{out} = 100\Omega \rightarrow$  find closed loop  $R_{out}$ ?



## *Example 3*

## Example 4

- Find bias currents, gain, input and output resistance.

